COMPLIANT

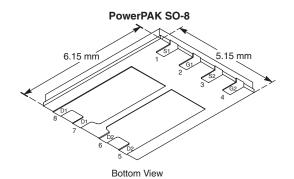
HALOGEN

FREE



Dual N-Channel 150-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
150	0.150 at V _{GS} = 10 V	3.3		
	0.168 at V _{GS} = 6 V	3.1		



Ordering Information: Si7946DP-T1-E3 (Lead (Pb)-free)

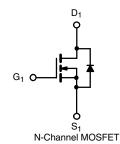
Si7946DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

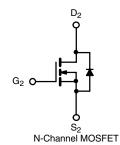
FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFETs
- New Low Thermal Resistance PowerPAK[®] Package
- Dual MOSFET for Space Savings
- · PWM Optimized for Fast Switching
- Avalanche Rated

APPLICATIONS

Primary Side Switch





ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unle	ss otherwise n	oted			
Parameter	Symbol	10 s	Steady State	Unit		
Drain-Source Voltage		V_{DS}	150		V	
Gate-Source Voltage		V _{GS}	± 20		V	
Continuous Drain Current (T _{.I} = 150 °C) ^a	T _A = 25 °C	I_	3.3	2.1		
Continuous Drain Current (1) = 150 °C)	T _A = 70 °C	l _D	2.6	1.7		
Pulsed Drain Current		I _{DM}	10		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	2.9	1.2		
Single Avalanche Current L = 0.1 mH		I _{AS}	9			
Single Avalanche Energy		E _{AS}	4		mJ	
Marian and David Discipation a	T _A = 25 °C	P _D	3.5	1.4	W	
Maximum Power Dissipation ^a	T _A = 70 °C	ם י ט	2.2	0.9	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature) ^{b, c}			260			

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Manianum lumation to Ambienta	t ≤ 10 s	R _{thJA}	26	35		
Maximum Junction-to-Ambient ^a	Steady State	' 'thJA	60	85	°C/W	
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	3.2	4.2		

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (<u>www.vishay.com/ppg?73257</u>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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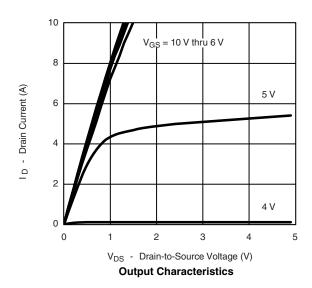
SPECIFICATIONS $T_J = 25$	°C, unless	otherwise noted				
Parameter	Symbol	Test Condition Min.		Тур.	Max.	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2		4.0	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zero Gate Voltage Drain Current	1	V _{DS} = 150 V, V _{GS} = 0 V			1	
Zero Gate voltage Drain Current	I _{DSS}	V _{DS} = 150 V, V _{GS} = 0 V, T _J = 55 °C			5	μΑ
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			Α
5	В	$V_{GS} = 10 \text{ V}, I_D = 3.3 \text{ A}$		0.124	0.150	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 6 \text{ V}, I_D = 3.1 \text{ A}$		0.137	0.168	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 3.3 A		9		S
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.87	1.2	V
Dynamic ^b						
Total Gate Charge	Q_g			12.6	20	nC
Gate-Source Charge	Q_gs	$V_{DS} = 75 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 3.3 \text{ A}$		2.8		
Gate-Drain Charge	Q_{gd}			4.5		
Gate Resistance	R_g	f = 1 MHz		3.5		Ω
Turn-On Delay Time	t _{d(on)}			11	20	
Rise Time	t _r	V_{DD} = 75 V, R_L = 75 Ω		15	25	ns
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$		30	45	
Fall Time	t _f			20	30	
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = 2.9 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		62	100	

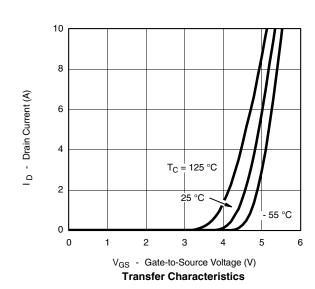
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



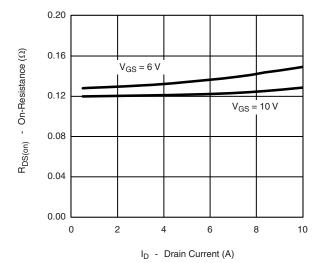




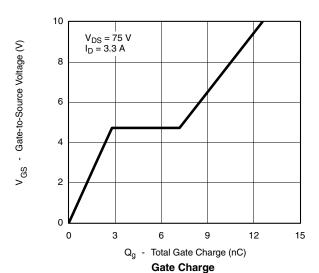


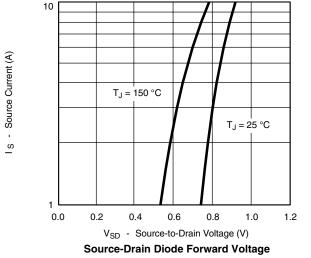


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

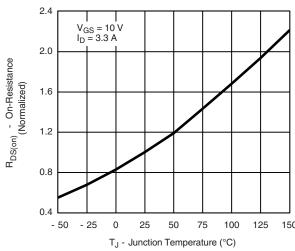


On-Resistance vs. Drain Current

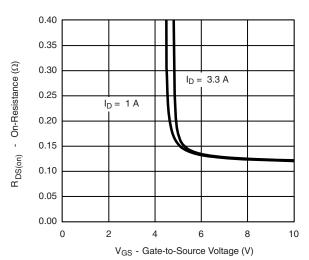




1000 800 C - Capacitance (pF) Ciss 600 400 200 $\mathsf{C}_{\mathsf{rss}}$ 0 10 20 30 40 50 60 70 80



On-Resistance vs. Junction Temperature

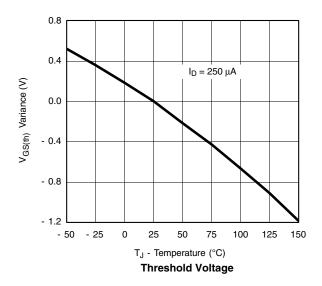


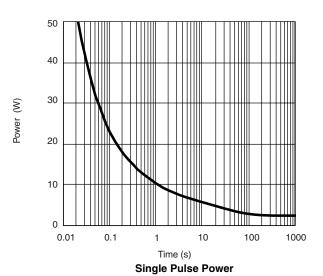
On-Resistance vs. Gate-to-Source Voltage

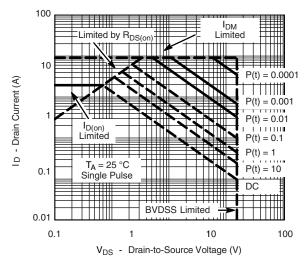
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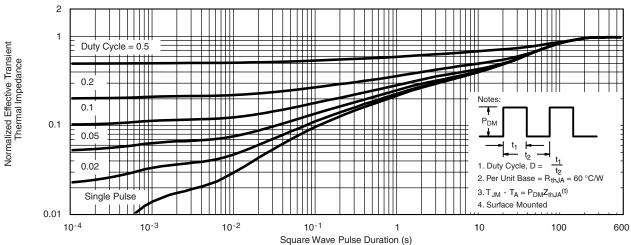
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





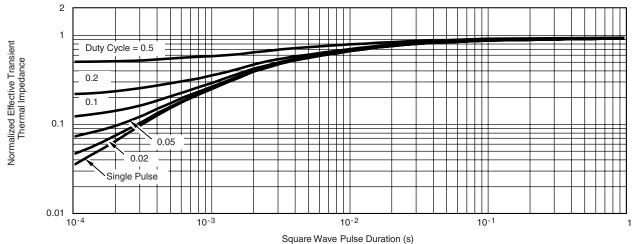


Safe Operating Area, Junction-to-Ambient





TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



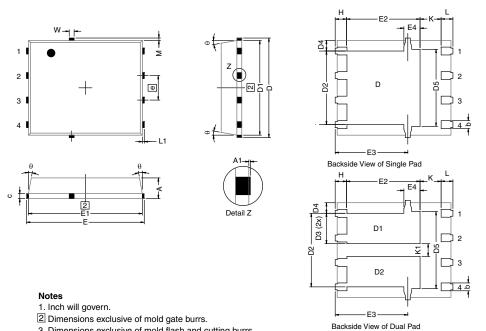
Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72282.



DWG: 5881

PowerPAK® SO-8, (Single/Dual)



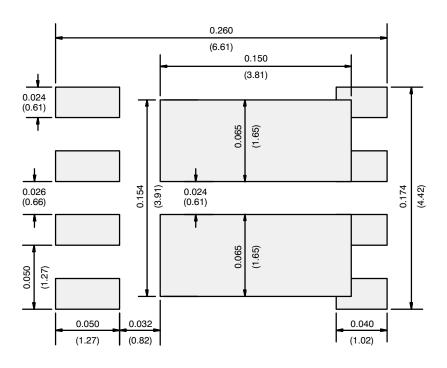
3. Dimensions exclusive of mold flash and cutting burrs.								
DIM.		MILLIMETERS			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
A	0.97	1.04	1.12	0.038	0.041	0.044		
A1		-	0.05	0	-	0.002		
b	0.33	0.41	0.51	0.013	0.016	0.020		
С	0.23	0.28	0.33	0.009	0.011	0.013		
D	5.05	5.15	5.26	0.199	0.203	0.207		
	4.00	4.00	F 00	0.400	0.400	0.407		

Α	0.97	1.04	1.12	0.038	0.041	0.044	
A1		-	0.05	0	-	0.002	
b	0.33	0.41	0.51	0.013	0.016	0.020	
С	0.23	0.28	0.33	0.009	0.011	0.013	
D	5.05	5.15	5.26	0.199	0.203	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.56	3.76	3.91	0.140	0.148	0.154	
D3	1.32	1.50	1.68	0.052	0.059	0.066	
D4		0.57 typ.			0.0225 typ.		
D5		3.98 typ.		0.157 typ.			
E	6.05	6.15	6.25	0.238	0.242	0.246	
E1	5.79	5.89	5.99	0.228	0.232	0.236	
E2 (for AL product)	3.30	3.48	3.66	0.130	0.137	0.144	
E2 (for other product)	3.48	3.66	3.84	0.137	0.144	0.151	
E3	3.68	3.78	3.91	0.145	0.149	0.154	
E4 (for AL product)		0.58 typ.		0.023 typ.			
E4 (for other product)		0.75 typ.			0.030 typ.		
е		1.27 BSC			0.050 BSC		
K (for AL product)		1.45 typ.		0.057 typ.			
K (for other product)		1.27 typ.		0.050 typ.			
K1	0.56	-	=	0.022	-	=	
Н	0.51	0.61	0.71	0.020	0.024	0.028	
L	0.51	0.61	0.71	0.020	0.024	0.028	
L1	0.06	0.13	0.20	0.002	0.005	0.008	
θ	0°	-	12°	0°	-	12°	
W	0.15	0.25	0.36	0.006	0.010	0.014	
M	0.125 typ.			0.005 typ.			
ECN: C13-0702-Rev. K, 20)-May-13			•			

Revison: 20-May-13 Document Number: 71655



RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Dual



Recommended Minimum Pads Dimensions in Inches/(mm)

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Revision: 02-Oct-12 Document Number: 91000